

# **isc Silicon NPN Power Transistor**

# 2SD2137A

## **DESCRIPTION**

- · Silicon NPN triple diffusion planar type
- · Complementary to 2SB1417A
- · Low Collector to Emitter Saturation Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation
- · Allowing supply with the radial taping

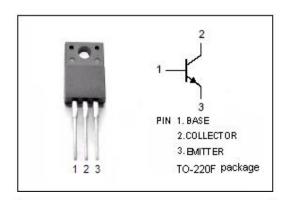


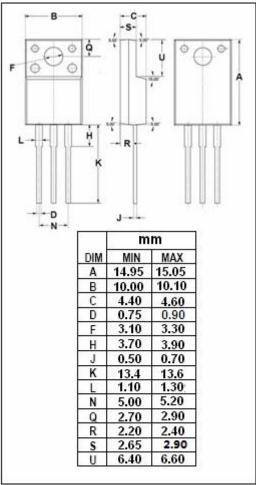
## **APPLICATIONS**

· Designed for power amplifiers



SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	80	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V	
V <sub>EBO</sub>	Emitter-Base Voltage 6		V	
lc	Collector Current-Continuous	3	Α	
I <sub>CM</sub>	Collector Current-Pulse 5			
D	Total Power Dissipation @T <sub>C</sub> =25℃	15 W		
$P_T$	Total Power Dissipation @T <sub>a</sub> =25°C	2		
TJ	Junction Temperature	150 °C		
T <sub>stg</sub>	Storage Temperature -55~150		$\mathbb{C}$	







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#### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> =30mA, Ib=0	80			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	Ic= 3A; I <sub>B</sub> = 0.375A			1.2	V
V <sub>BE(ON)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 3A; V <sub>CE</sub> = 4V			1.8	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 80V; I <sub>E</sub> = 0			100	μА
Iceo	Collector Cutoff Current	V <sub>CE</sub> = 60V; Ib=0			100	μ <b>А</b>
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 6V; I <sub>C</sub> = 0			100	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 4V	70		250	
h <sub>FE-2</sub>	DC Current Gain	Ic= 3A; VcE=4V	10			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.2A; V <sub>CE</sub> = 5V		30		MHz
Switching times						
t <sub>on</sub>	Turn-on Time			0.3		μS
t <sub>stg</sub>	Storage Time	$I_{C}$ = 1A $I_{B1}$ = - $I_{B2}$ = 0.1A, $V_{CC}$ $\approx$ 50V		2.5		μS
t <sub>f</sub>	Fall Time			0.2		μ <b>S</b>

### ♦ h<sub>FE-1</sub> Classifications

Q	Р		
70-150	120-250		

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